# SMD Type



## Switching Diodes BAV70 (KAV70)

- Features
- Small plastic SMD package.
- High switching sped: max.4 ns.
- Repetitive peak forward current: max.450 mA.





#### ■ Absolute Maximum Ratings Ta = 25°C

| Parameter  | Symbol | Rating   | Unit        |     |
|--|--------|----------|-------------|-----|
| Repetitive peak reverse voltage  |        | Vrrm     | 85          | V   |
| Continuous reverse voltage   |        | Vr       | 75          | V   |
| Continuous forward current(single diode loaded *)<br>(double diode loaded *) |        | lF       | 215<br>125  | mA  |
| Repetitive peak forward current  |        | IFRM     | 450         | mA  |
| Non-repetitive peak forward current Tj=25 $^\circ\!\!C$ t=1 $\mu$ s          |        |          | 4           |     |
| t=   | 1ms    | IFSM     | 1           | А   |
| t=   | =1s    |          | 0.5         |     |
| power dissipation *  |        | PD       | 250         | mW  |
| Thermal resistance from junction to tie-point                                |        | Rth j-tp | 360         | K/W |
| Thermal resistance from junction to ambient *                                |        | Rth j-a  | 500         | K/W |
| Junction Temperature   |        | Tj       | 150         | °C  |
| Storage Temperature Range  |        | Tstg     | -65 to +150 | °C  |

\* Device mounted on an FR4 printed-circuit board.

■ Electrical Characteristics Ta = 25°C

| Parameter                | Symbol | Test conditions   |               | Unit |
|--------------------------|--------|---|---------------|------|
| Forward voltage          | VF     | IF =1 mA  |               | mV   |
|                          |        | IF =10 mA   |               | mV   |
|                          |        | IF =50 mA   |               | V    |
|                          |        | IF =150 mA  |               | V    |
| Reverse current          | lr     | VR =75 V<br>VR =25 V; Tj= 150 ℃<br>VR =75 V; Tj= 150 ℃                        | 1<br>30<br>50 | μ Α  |
| Diode capacitance        | Cd     | VR =0 V, f= 1 MHz   | 1.5           | pF   |
| Reverse recovery time    | trr    | when switched from IF= 10 mA to IR=10mA;RL=100 $\Omega$ ; measured at IR= 1mA |               | nS   |
| Forward recovery voltage | Vfr    | I⊧ = 10 mA, tr= 20 ns   | 1.75          | V    |

#### Marking

Marking A4\*



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Diodes

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#### Typical Characteristics



Device mounted on an FR4 printed-circuit board.

Fig.2 Maximum permissible continuous forward current as a function of ambient temperature.



- (1)  $T_j = 150 \text{ °C}$ ; typical values.
- (2)  $T_j = 25 \circ C$ ; typical values.
- (3)  $T_j = 25 \text{ °C}$ ; maximum values.
- Fig.3 Forward current as a function of forward voltage.



 $T_j = 25 \text{ °C prior to surge.}$ 

Fig.4 Maximum permissible non-repetitive peak forward current as a function of pulse duration.



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Diodes



Fig.5 Reverse current as a function of junction temperature.



f = 1 MHz; T<sub>j</sub> = 25 °C.

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Fig.6 Diode capacitance as a function of reverse voltage; typical values.



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